

isc N-Channel MOSFET Transistor

IRF3007, IIRF3007

FEATURES

- Static drain-source on-resistance: R_Ds(on) ≤12.6mΩ
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

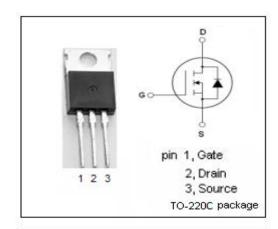
• reliable device for use in a wide variety of applications

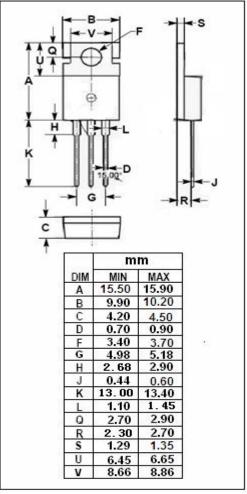
• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	75	V				
V _{GS}	Gate-Source Voltage	±20	V				
I _D	Drain Current-Continuous	75	А				
I _{DM}	Drain Current-Single Pulsed	320	А				
P _D	Total Dissipation @T _C =25°C	200	W				
Tj	Max. Operating Junction Temperature 17		$^{\circ}$ C				
T _{stg}	Storage Temperature	-55~175	$^{\circ}$				

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.74	°C/W
Rth(ch-a)	ch-a) Channel-to-ambient thermal resistance		°C/W







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	75			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10V; ID =250 μ A	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =48A			12.6	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V			±0.2	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =75V; V _{GS} = 0V			20	μ А
V _{SD}	Diode forward voltage	Is=48A, V _{GS} = 0V			1.3	V

NOTICE:

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